

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Jan Bartlomiej Pawlak et al.  
Appl. No. : 10/596,612  
Filed : June 19, 2006  
For : SEMICONDUCTOR SUBSTRATE WITH  
SOLID PHASE EPITAXIAL REGROWTH  
WITH REDUCED JUNCTION LEAKAGE  
AND METHOD OF PRODUCING SAME  
Examiner : Ghyka, Alexander G.  
Group Art Unit : 2812

COMMENTS ON EXAMINER'S STATEMENT OF REASONS FOR ALLOWANCE

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Sir:

Applicant wishes to address the Examiner's statement of reasons for allowance in the Notice of Allowability mailed February 2, 2012. Applicant respectfully submits that the claims should be allowed based on the entire language rather than focusing on any specific portion thereof as described in the Notice of Allowability. Please charge any additional fees, including any fees for additional extension of time, or credit overpayment to Deposit Account No. 11-1410.

Respectfully submitted,

KNOBBE, MARTENS, OLSON & BEAR, LLP

Dated: 5/1/12

By: 

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